## TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74AC32P,TC74AC32F,TC74AC32FN,TC74AC32FT

#### Quad 2-Input OR Gate

The TC74AC32 is an advanced high speed CMOS 2-INPUT OR GATE fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 2 stages including buffer output, which provide high noise immunity and stable output.

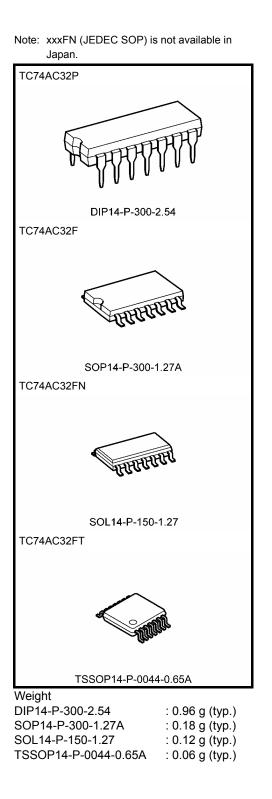
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

- High speed:  $t_{pd}$  = 4.1 ns (typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$

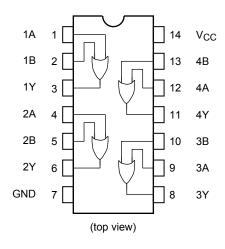
transmission lines.

- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 to 5.5 V
- Pin and function compatible with 74F32

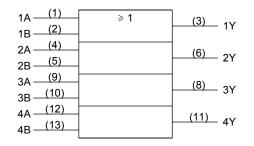


# <u>TOSHIBA</u>

## **Pin Assignment**



#### **IEC Logic Symbol**



#### Truth Table

А	В	Y
Н	Н	Н
L	Н	Н
Н	L	Н
L	L	L

## Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIК	±20	mA
Output diode current	I <sub>OK</sub>	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	ICC	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = $3.3 \pm 0.3$ V)	ns/V
	uvuv	0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)	115/ V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Test Condition			Ta = 25°C		Ta = −40 to 85°C		Unit		
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit	
		_		2.0	1.50	_	_	1.50	_	v	
High-level input voltage	VIH			3.0	2.10	—	—	2.10	—		
Ŭ					5.5	3.85	_	_	3.85		
		_		2.0	—	—	0.50	—	0.50		
Low-level input voltage	VIL			3.0	—	—	0.90	—	0.90	V	
Ŭ					5.5	—	_	1.65		1.65	
			I <sub>OH</sub> = −50 μA		2.0	1.9	2.0	—	1.9	—	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		3.0	2.9	3.0	—	2.9	—	v	
High-level output	V <sub>OH</sub>			4.5	4.4	4.5	—	4.4	-		
voltage	VOH		I <sub>OH</sub> = −4 mA		3.0	2.58	—	—	2.48		v
			I <sub>OH</sub> = −24 mA		4.5	3.94	—	—	3.80	—	
			I <sub>OH</sub> = −75 mA	(Note)	5.5	—	—	—	3.85	-	
		V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 50 μΑ		2.0	—	0.0	0.1		0.1	
					3.0	—	0.0	0.1	—	0.1	v
Low-level output voltage	V <sub>OL</sub>				4.5	—	0.0	0.1		0.1	
	VOL		I <sub>OL</sub> = 12 mA		3.0	—	—	0.36		0.44	
			I <sub>OL</sub> = 24 mA		4.5	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	—	—	—	-	1.65	
Input leakage current	۱ <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	—	—	±0.1		±1.0	μA
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	_	4.0		40.0	μA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

### AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	-,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub>		3.3 ± 0.3	_	6.1	10.3	1.0	11.9	20
	t <sub>pHL</sub>	—	$5.0 \pm 0.5$	—	5.2	7.4	1.0	8.5	ns
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note)	_	64	_	—	—	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

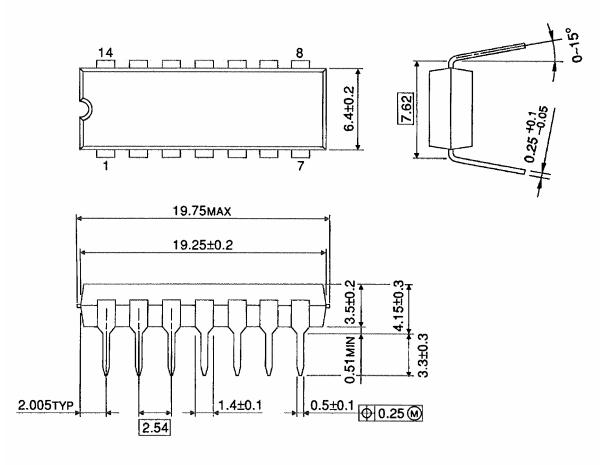
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per gate)

## **Package Dimensions**

DIP14-P-300-2.54

Unit : mm



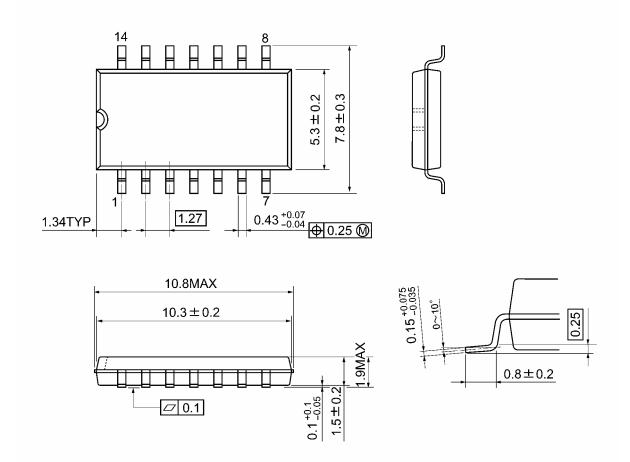
Weight: 0.96 g (typ.)



## **Package Dimensions**

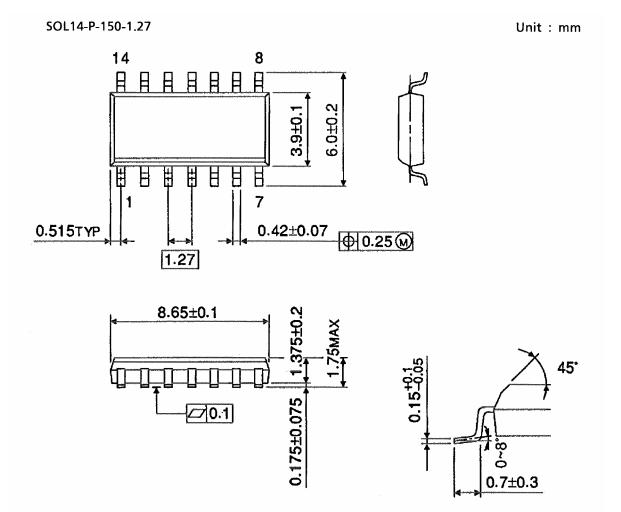
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

## Package Dimensions (Note)



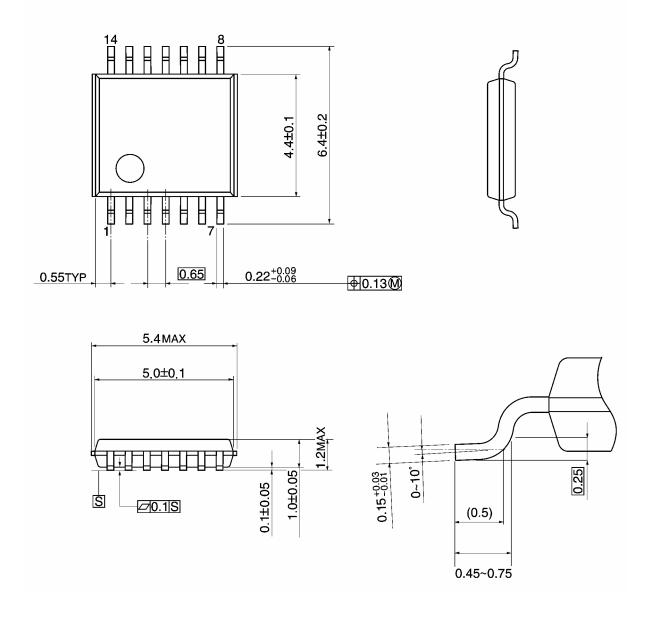
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

## Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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